# **Dual P-Channel 30-V (D-S) MOSFET**

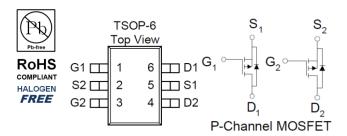
### **Key Features:**

- Low r<sub>DS(on)</sub> trench technology
- · Low thermal impedance
- · Fast switching speed

<b>Typical Applications:</b>
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- · White LED boost converters
- Automotive Systems
- Industrial DC/DC Conversion Circuits

PRODUCT SUMMARY			
V <sub>DS</sub> (V)	$r_{DS(on)}(m\Omega)$	I□ (A)	
-30	56 @ V <sub>GS</sub> = -10V	-3.8	
-30	86 @ V <sub>GS</sub> = -4.5V	-3.0	



ABSOLUTE MAXIMUM RATINGS (T <sub>A</sub> = 25°C UNLESS OTHERWISE NOTED)					
Parameter		Symbol	Limit	Units	
Drain-Source Voltage			-30	V	
Gate-Source Voltage	$V_{GS}$	±20	V		
Continuous Brain Commental	T <sub>A</sub> =25°C	ı	-3.8		
Continuous Drain Current a	T <sub>A</sub> =70°C	- I <sub>D</sub>	-2.9	Α	
Pulsed Drain Current <sup>b</sup>	I <sub>DM</sub>	-15	'		
Continuous Source Current (Diode Conduction) a		I <sub>S</sub>	-2.3	Α	
Devices Discipation <sup>a</sup>	T <sub>A</sub> =25°C	$P_{D}$	1.15	W	
Power Dissipation <sup>a</sup>	T <sub>A</sub> =70°C	L.D	0.7	۷V	
Operating Junction and Storage Temperature Range	-	$T_J$ , $T_{stg}$	-55 to 150	°C	

THERMAL RESISTANCE RATINGS					
Parameter			Maximum	Units	
Maximum Junction-to-Ambient <sup>a</sup>	t <= 10 sec	$R_{\theta JA}$	110	°C/W	
IMAXIMUM Sunction-to-Ambient	Steady State	IΛθJA	150	C/VV	

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#### Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

### **Electrical Characteristics**

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Static						
Gate-Source Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_{D} = -250 \text{ uA}$	-1			V
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			±100	nA
Zero Gate Voltage Drain Current	1	$V_{DS} = -24 \text{ V}, V_{GS} = 0 \text{ V}$			-1	— uA
Zelo Gate Voltage Brain Current	I <sub>DSS</sub>	$V_{DS} = -24 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			-10	
On-State Drain Current <sup>a</sup>	I <sub>D(on)</sub>	$V_{DS} = -5 \text{ V}, V_{GS} = -10 \text{ V}$	-5.7			Α
Drain Cauras On Basistanas a	r	$V_{GS} = -10 \text{ V}, I_{D} = -3 \text{ A}$			56	mΩ
Drain-Source On-Resistance <sup>a</sup>	r <sub>DS(on)</sub>	$V_{GS} = -4.5 \text{ V}, I_D = -2 \text{ A}$			86	11122
Forward Transconductance a	g <sub>fs</sub>	$V_{DS} = -15 \text{ V}, I_{D} = -3 \text{ A}$		6		S
Diode Forward Voltage <sup>a</sup>	$V_{SD}$	$I_S = -1.2 \text{ A}, V_{GS} = 0 \text{ V}$		-0.84		V
Dynamic <sup>b</sup>						
Total Gate Charge	$Q_g$	$V_{DS} = -15 \text{ V}, V_{GS} = -4.5 \text{ V},$		8		
Gate-Source Charge	$Q_{gs}$	$I_{D} = -2 \text{ A}$		2.4		nC
Gate-Drain Charge	$Q_gd$	1D - 2 A		2.6		
Turn-On Delay Time	t <sub>d(on)</sub>	$V_{DS} = -15 \text{ V}, R_1 = 7.5 \Omega,$		6		
Rise Time	t <sub>r</sub>	$V_{DS} = -15 \text{ V}, K_L - 7.5 \Omega,$ $I_D = -2 \text{ A},$		8		no
Turn-Off Delay Time	$t_{d(off)}$	$V_{GEN} = -10 \text{ V}, R_{GEN} = 6 \Omega$		28		ns
Fall Time	t <sub>f</sub>	VGEN = 10 V, 11GEN = 0 12		11		
Input Capacitance	C <sub>iss</sub>			604		
Output Capacitance	C <sub>oss</sub>	$V_{DS} = -15 \text{ V}, V_{GS} = 0 \text{ V}, f = 1 \text{ Mhz}$		58		pF
Reverse Transfer Capacitance	$C_{rss}$			49		

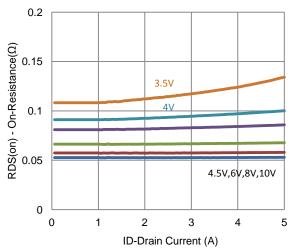
#### **Notes**

- a. Pulse test: PW <= 300us duty cycle <= 2%.
- b. Guaranteed by design, not subject to production testing.

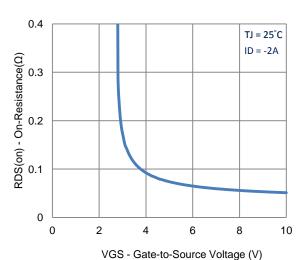
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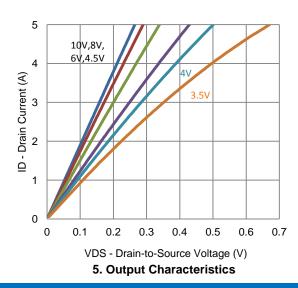
## **Typical Electrical Characteristics**



#### 1. On-Resistance vs. Drain Current



3. On-Resistance vs. Gate-to-Source Voltage

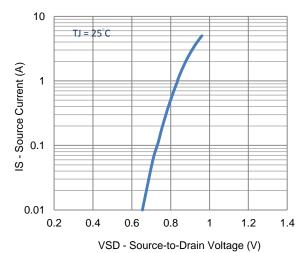


TJ = 25°C

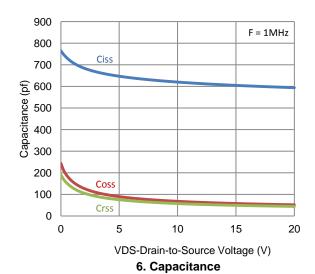
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VGS - Gate-to-Source Voltage (V)

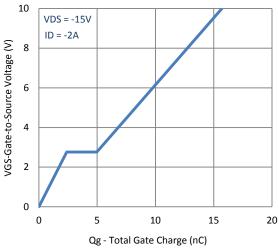
2. Transfer Characteristics



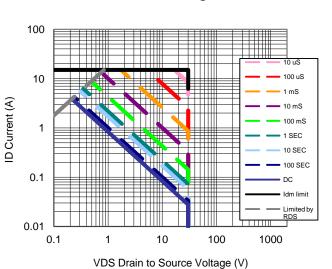
4. Drain-to-Source Forward Voltage



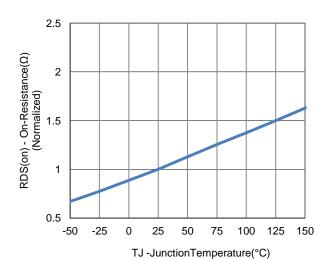
## **Typical Electrical Characteristics**



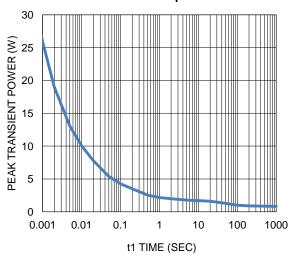
7. Gate Charge



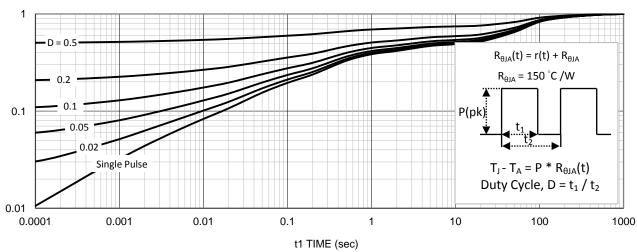
9. Safe Operating Area



8. Normalized On-Resistance Vs Junction Temperature

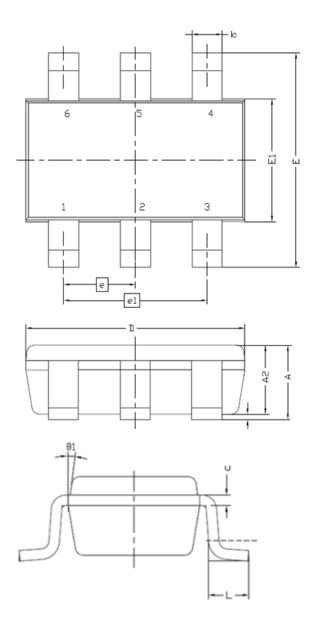


10. Single Pulse Maximum Power Dissipation



11. Normalized Thermal Transient Junction to Ambient

## **Package Information**



Symbol	MILLIMETERS		
Syllibol	MIN	MAX	
Α	0.8	1.2	
A1	0	0.1	
A2	0.7	1.1	
b	0.3	0.5	
С	0.1	0.2	
D	2.8	3.1	
Е	2.6	3	
E1	1.4	1.7	
е	0.9	1	
e1	1.8	2	
L	0.3	0.6	
θ1	7° NOM		

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